



RF MOSFET Power Transistor, 5W, 28V

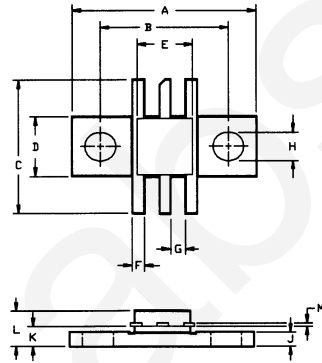
100 - 500 MHz

UF2805B

V2.00

Features

- N-Channel Enhancement Mode Device
- DMOS Structure
- Lower Capacitances for Broadband Operation
- Common Source Configuration
- Lower Noise Floor
- 100 MHz to 500 MHz Operation



Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	65	V
Gate-Source Voltage	V_{GS}	20	V
Drain-Source Current	I_{DS}	1.4	A
Power Dissipation	P_D	14.4	W
Junction Temperature	T_J	200	°C
Storage Temperature	T_{STG}	-55 to +150	°C
Thermal Resistance	θ_{JC}	12.1	°C/W

LETTER DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	20.70	20.96	.815	.825
B	14.35	14.61	.565	.575
C	14.73	15.24	.580	.600
D	6.27	6.53	.247	.257
E	6.22	6.48	.245	.255
F	1.14	1.40	.045	.055
G	1.52	1.78	.060	.070
H	2.92	3.17	.115	.125
J	1.40	1.65	.055	.065
K	2.03	2.39	.080	.094
L	3.66	4.32	.144	.170
M	.10	.15	.004	.006

Electrical Characteristics at 25°C

Parameter	Symbol	Min	Max	Units	Test Conditions
Drain-Source Breakdown Voltage	BV_{DSS}	65	-	V	$V_{GS}=0.0\text{ V}$, $I_{DS}=2.0\text{ mA}$
Drain-Source Leakage Current	I_{DSS}	-	1.0	mA	$V_{DS}=28.0\text{ V}$, $V_{GS}=0.0\text{ V}$
Gate-Source Leakage Current	I_{GSS}	-	1.0	μA	$V_{GS}=20\text{ V}$, $V_{DS}=0.0\text{ V}$
Gate Threshold Voltage	$V_{GS(TH)}$	2.0	6.0	V	$V_{DS}=10.0\text{ V}$, $I_{DS}=10.0\text{ mA}$
Forward Transconductance	G_M	80	-	mS	$V_{DS}=10.0\text{ V}$, $I_{DS}=100.0\text{ mA}$, $\Delta V_{GS}=1.0\text{ V}$, 80 μs Pulse
Input Capacitance	C_{ISS}	-	7	pF	$V_{DS}=28.0\text{ V}$, $F=1.0\text{ MHz}$
Output Capacitance	C_{OSS}	-	5	pF	$V_{DS}=28.0\text{ V}$, $F=1.0\text{ MHz}$
Reverse Capacitance	C_{RSS}	-	2.4	pF	$V_{DS}=28.0\text{ V}$, $F=1.0\text{ MHz}$
Power Gain	G_P	10	-	dB	$V_{DD}=28.0\text{ V}$, $I_{DQ}=50.0\text{ mA}$, $P_{OUT}=5.0\text{ W}$, $F=500\text{ MHz}$
Drain Efficiency	η_D	50	-	%	$V_{DD}=28.0\text{ V}$, $I_{DQ}=50.0\text{ mA}$, $P_{OUT}=5.0\text{ W}$, $F=500\text{ MHz}$
Load Mismatch Tolerance	VSWR-T	-	20:1	-	$V_{DD}=28.0\text{ V}$, $I_{DQ}=50.0\text{ mA}$, $P_{OUT}=5.0\text{ W}$, $F=500\text{ MHz}$

Specifications Subject to Change Without Notice.

M/A-COM, Inc.

North America: Tel. (800) 366-2266
Fax (800) 618-8883

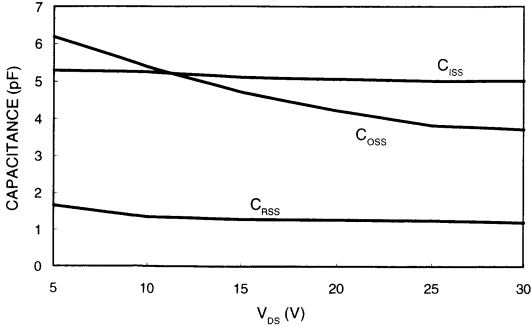
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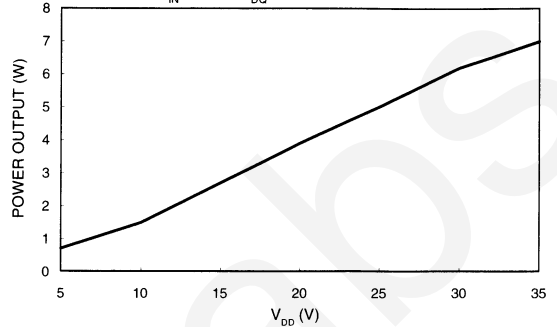
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Typical Broadband Performance Curves

CAPACITANCES vs VOLTAGE
F=1.0 MHz

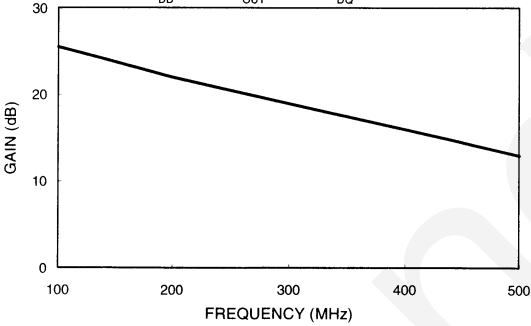


POWER OUTPUT vs VOLTAGE
 $P_{IN}=0.3\text{ W}$ $I_{D0}=5.0\text{ mA}$ F=500 MHz



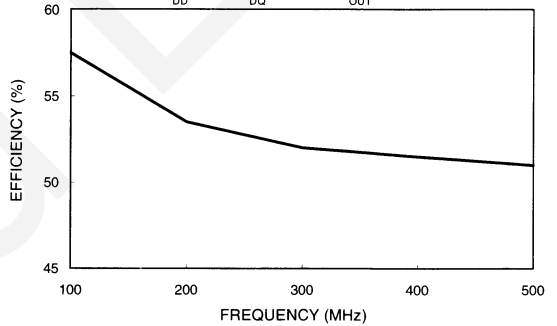
GAIN vs FREQUENCY

$V_{DD}=28\text{ V}$ $P_{OUT}=5.0\text{ W}$ $I_{D0}=50\text{ mA}$



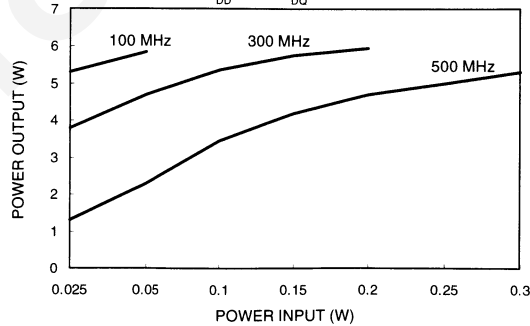
EFFICIENCY vs FREQUENCY

$V_{DD}=28\text{ V}$ $I_{D0}=50\text{ mA}$ $P_{OUT}=5.0\text{ W}$



POWER OUTPUT vs POWER INPUT

$V_{DD}=28\text{ V}$ $I_{D0}=50\text{ mA}$



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Typical Device Impedance

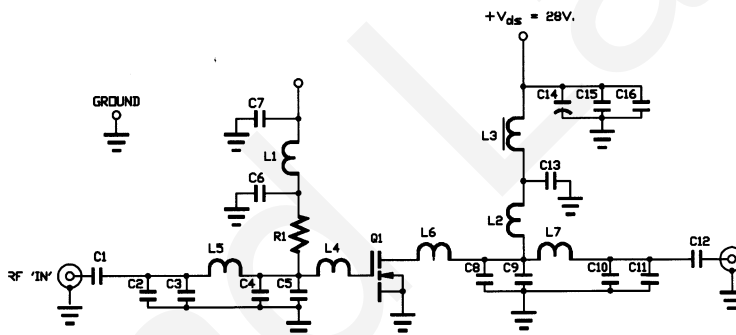
Frequency (MHz)	Z_{IN} (OHMS)	Z_{LOAD} (OHMS)
100	15.0 - j 80.0	35.0 + j 55.0
300	8.0 - j 43.0	29.0 + j 40.0
500	4.0 - j 29.0	28.0 + j 29.0

$$V_{DD}=28 \text{ V}, I_{DQ}=50 \text{ mA}, P_{OUT}=5.0 \text{ Watts}$$

Z_{IN} is the series equivalent input impedance of the device from gate to source.

Z_{LOAD} is the optimum series equivalent load impedance as measured from drain to drain.

RF Test Fixture



PARTS LIST

C8	1.0pf
C9	3.9pf
C4, 10, 11	4.7pf
C2	5.6pf
C3	8.2pf
C5	15pf
C6, 7, 13, 16	680pf
C1, 12	820pf
C15	.01uf
C14	50uf 50V.
R1	10K OHM
Q1	UF2805B
L1	9 TURNS OF NO. 24 AWG
L2	7 TURNS OF NO. 22 AWG
L3	3 TURNS OF NO. 24 AWG ON FERRITE BEAD
L4	1.30' OF 50 OHM TRANSMISSION LINE
L5	.70' OF 50 OHM TRANSMISSION LINE
L6	.20' OF 50 OHM TRANSMISSION LINE
L7	1.85' OF 50 OHM TRANSMISSION LINE

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